

# RD74LVC1G86

## 2-input Exclusive OR Gate

REJ03D0728-0100 Rev.1.00 Jul 26, 2006

### **Description**

The RD74LVC1G86 has two–input Exclusive OR gate in a 5-pin package. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

#### **Features**

• The basic gate function is lined up as renesas uni logic series.

• Supply voltage range: 1.65 to 5.5 V Operating temperature range: -40 to +85°C

• All inputs:  $V_{IH}$  (Max.) = 5.5 V (@V<sub>CC</sub> = 0 V to 5.5 V)

All outputs:  $V_0$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V)

• Output current:  $\pm 4 \text{ mA } (@V_{CC} = 1.65 \text{ V})$ 

 $\pm 8 \text{ mA } (@V_{CC} = 2.3 \text{ V})$ 

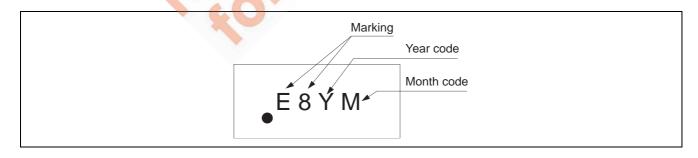
 $\pm 24 \text{ mA } (@V_{CC} = 3.0 \text{ V})$ 

 $\pm 32 \text{ mA } (@V_{CC} = 4.5 \text{ V})$ 

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
RD74LVC1G86WPE	WCSP-5 pin	SXBG0005LB-A (TBS-5CV)	WP	E (3,000 pcs/reel)

#### **Article indication**



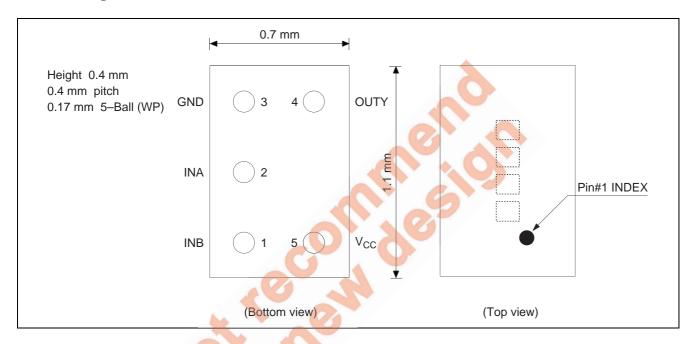
### **Function Table**

Inp	Output V	
Α	В	Output Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L

H: High level

L: Low level

## **Pin Arrangement**



# Logic Diagram



## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	Vcc	-0.5 to 6.5	V	
Input voltage range *1	VI	-0.5 to 6.5	V	
Output voltage range *1, 2	V	$-0.5$ to $V_{CC}$ +0.5	V	Output : H or L
Output voltage range	Vo	-0.5 to 6.5	V	V <sub>CC</sub> : OFF
Input clamp current	I <sub>IK</sub>	-50	mA	V <sub>1</sub> < 0
Output clamp current	I <sub>OK</sub>	-50	mA	V <sub>O</sub> < 0
Continuous output current	Ιο	±50	mA	$V_{\rm O} = 0$ to $V_{\rm CC}$
Continuous current through	Icc or I <sub>GND</sub>	±100	mA	
V <sub>CC</sub> or GND	ICC OI IGND	±100	IIIA	
Package Thermal impedance	$\theta_{ja}$	200	°C/W	WP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.

## **Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V <sub>CC</sub>	1.65	5.5	2V	
Input voltage range	VI	0	5.5	V	
Output voltage range	Vo	0	Vcc	V	
		<b>S</b> - 1	4		V <sub>CC</sub> = 1.65 V
	100	-	8		$V_{CC} = 2.3 \text{ V}$
K	I <sub>OL</sub>		16		V <sub>CC</sub> = 3.0 V
			24		VCC = 3.0 V
Output current			32	m Λ	$V_{CC} = 4.5 \text{ V}$
Output current	1	_	-4	mA	V <sub>CC</sub> = 1.65 V
		_	-8		$V_{CC} = 2.3 \text{ V}$
	Іон	_	-16		V <sub>CC</sub> = 3.0 V
		_	-24		VCC = 3.0 V
		_	-32		$V_{CC} = 4.5 \text{ V}$
		0	20		$V_{CC} = 1.65 \text{ to } 1.95 \text{ V},$
Input transition rise or fall rate	Δt / Δv	Ů	20	ns / V	2.3 to 2.7 V
input transition rise of fall fale	Δι/Δν	0	10	113 / V	$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		0	5		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Operating free-air temperature	Ta	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

## **Electrical Characteristics**

Ta = -40 to  $85^{\circ}C$ 

Item	Symbol	V <sub>CC</sub> (V)	Min	Тур	Max	Unit	Test condition
		1.65 to 1.95	V <sub>CC</sub> ×0.65	_	_		
	VIH	2.3 to 2.7	1.7	_	_		
	VIH	3.0 to 3.6	2.0	_	_		
Innut voltage		4.5 to 5.5	V <sub>CC</sub> ×0.7	_	_	V	
Input voltage		1.65 to 1.95	_	_	V <sub>CC</sub> ×0.35	V	
	\ \ <u>\</u>	2.3 to 2.7	_	_	0.7		
	V <sub>IL</sub>	3.0 to 3.6	_	_	0.8		
		4.5 to 5.5	_	_	V <sub>CC</sub> ×0.3		
		Min to Max	V <sub>CC</sub> -0.1	_	_		$I_{OH} = -100 \mu A$
		1.65	1.2	_	_		$I_{OH} = -4 \text{ mA}$
	V/	2.3	1.9	_	_		$I_{OH} = -8 \text{ mA}$
	V <sub>OH</sub>	3.0	2.4	_	-		I <sub>OH</sub> = -16 mA
		3.0	2.3	_	- 0		I <sub>OH</sub> = -24 mA
Output valtage		4.5	3.8	_	4	V	I <sub>OH</sub> = -32 mA
Output voltage		Min to Max	_	_	0.1	V	I <sub>OL</sub> = 100 μA
		1.65	_	4	0.45	10	I <sub>OL</sub> = 4 mA
		2.3	_	-	0.3		I <sub>OL</sub> = 8 mA
	V <sub>OL</sub>	3.0	-/-	1-	0.4	2	I <sub>OL</sub> = 16 mA
		3.0		<b>—</b>	0.55		I <sub>OL</sub> = 24 mA
		4.5			0.55		I <sub>OL</sub> = 32 mA
Input current	I <sub>IN</sub>	0 to 5.5			±5	μΑ	V <sub>IN</sub> = 5.5 V or GND
Quiescent	Icc	5.5		7	10		$V_{IN} = V_{CC}$ or GND, $I_O = 0$
supply current	A1	3 to 5.5	7		500	μΑ	One input at V <sub>CC</sub> -0.6 V,
зарріу сипені	Δlcc	3 10 3.5	11		300		Other input at V <sub>CC</sub> or GND
Output leakage current	I <sub>OFF</sub>	0		_	±10	μΑ	$V_{IN}$ or $V_O = 0$ to 5.5 V
Input capacitance	CIN	3.3		4.0	_	pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

# **Switching Characteristics**

 $V_{CC} = 1.8 \pm 0.15 \text{ V}$ 

Item	Symbol	Ta = -40 to 85°C		Unit	Test Conditions	FROM	ТО	
	Syllibol	Min	Max	Ollit	rest Conditions	(Input)	(Output)	
Dranagation dalay time	t <sub>PLH</sub> 2.1 9.1		$C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$	A or B	V			
Propagation delay time	t <sub>PHL</sub>	3.5	9.9		ns	$C_L = 30 \text{ pF}, R_L = 1.0 \text{ k}\Omega$	AUID	Ĭ

 $V_{CC}=2.5\pm0.2~V$ 

Item	Symbol Ta = -40		to 85°C	l lmi4	Test Conditions	FROM	то
	Symbol	Min	Max	Unit	rest Conditions	(Input)	(Output)
Dranagation dalay time	t <sub>PLH</sub> 1.0 4.5	4.5		$C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$	A or B	V	
Propagation delay time	$t_{PHL}$	1.8	5.5	ns	$C_L = 30 \text{ pF}, R_L = 500 \Omega$	AUID	Ī

 $V_{CC}=3.3\pm0.3~V$ 

Item	Cumbal	Ta = -40 to 85°C		Unit	Test Conditions	FROM	ТО
	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Dropogation dolay time	t <sub>PLH</sub> 0.6 4.0		$C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$	A or B	V		
Propagation delay time	$t_{PHL}$	1.3	5.0	ns	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	AUID	Ĭ

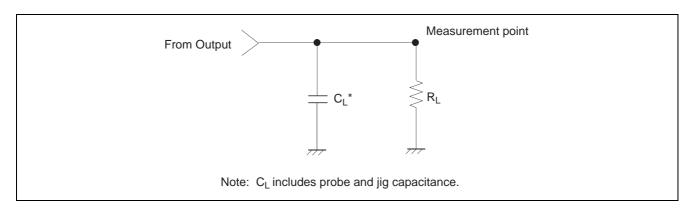
 $V_{CC}=5.0\pm0.5~V$ 

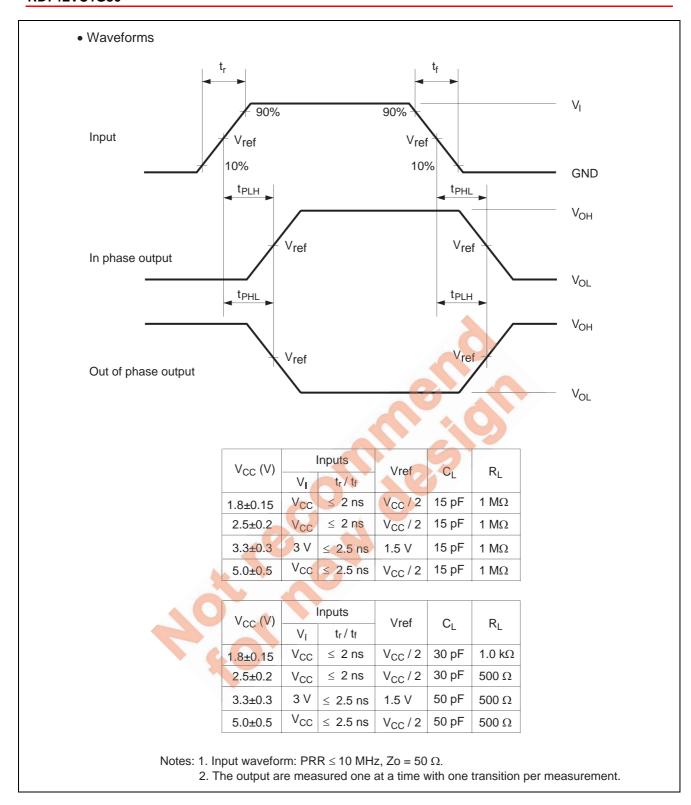
Item	Symbol	Ta = -40 to 85°C		Unit	Test Conditions	FROM	ТО
	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t <sub>PLH</sub>	0.8	3.3	nc	$C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$	A or B	V
	t <sub>PHL</sub>	1.0	4.0	ns	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	A or B	ſ

# **Operating Characteristics**

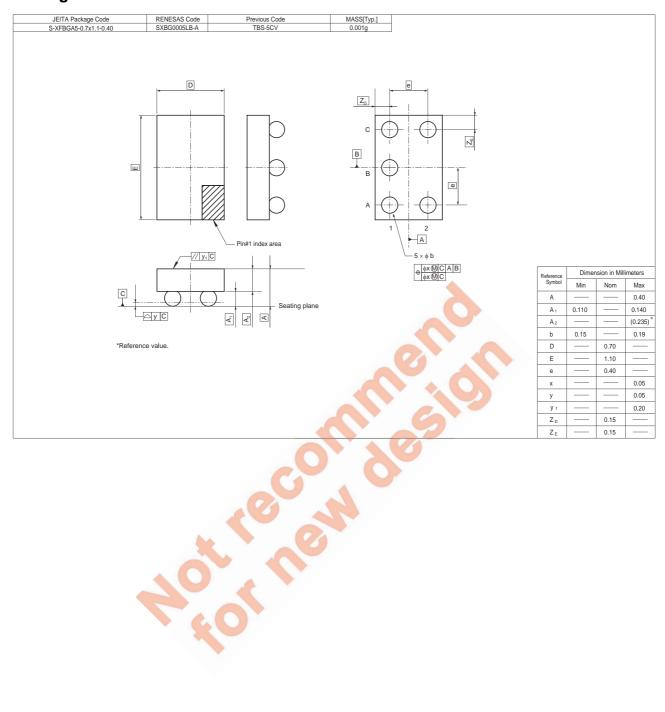
Item	Symbol	V AA	9	Ta = 25°C		Unit	Test Conditions
item	Syllibol	V <sub>CC</sub> (V)	Min	Тур	Max		
	9	1.8	_	20	_		f = 10 MHz
Dower dissinction consistence	0	2.5	_	20	_	pF	
Power dissipation capacitance	СРО	3.3	_	21	_		
		5.0	_	22	_		

### **Test Circuit**





### **Package Dimensions**



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